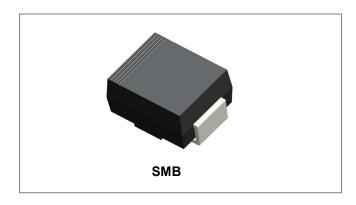


RoHS



SD360B STANDARD RECTIFIER



Features

- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Low Forward Voltage Drop
- Low Power Loss
- Built Strain Relief
- Plastic Case Material has UL Flammability Classification Rating 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- · Case: SMB molded plastic body
- Terminals: Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: AnyWeight: 0.09 grams

Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Characteristic	Symbol	SD360B	Units
Maximum Peak Repetitive Reverse Voltage Maximum DC Blocking Voltage	V _{RRM} V _{DC}	600	V
Maximum RMS Voltage	V _{RMS}	420	V
Maximum Average Forward Rectified Current 0.375"(9.5mm) Lead Length @T _A = 75°C	I _(AV)	3.0	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	120	А
Maximum Instantaneous Forward Voltage @I _F = 3.0A	V _F	1.2	V
Maximum DC Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 100°C	I _R	5.0 100	uA
Typical Junction Capacitance (Note 1)	Cj	30.0	pF
Typical Thermal Resistance (Note 2)	$R_{ heta JA}$	20.0	°C/W
Operating Storage Temperature Range	T _{STG}	-65 to +175	°C
Operating Junction Temperature	TJ	-65 to +175	°C

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

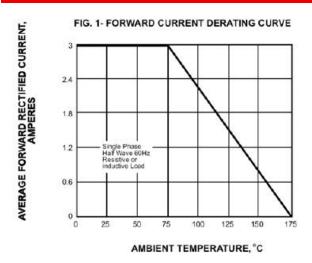
- 2. Thermal resistance from junction to ambient at 0.375"(9.5mm)lead length, P.C.B. mounted.
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 - http://www.smc-diodes.com
 sales@ smc-diodes.com



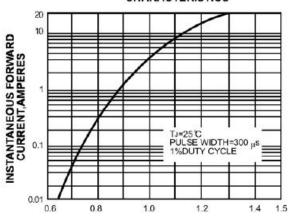




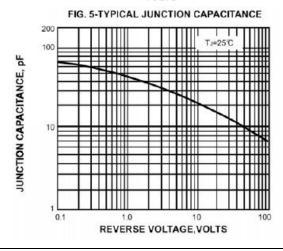
Ratings and Characteristics Curves

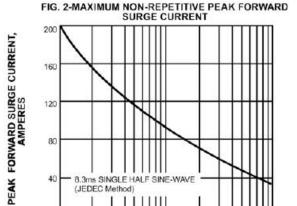






INSTANTANEOUS FORWARD VOLEAGE, VOLTS

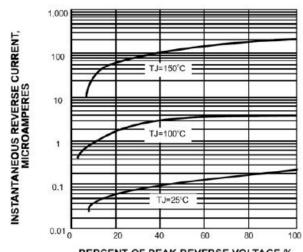




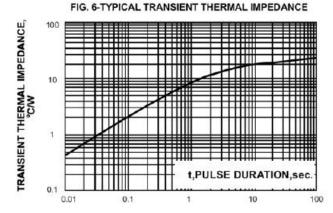
(JEDEC Method)

NUMBER OF CYCLES AT 60 Hz

FIG. 4-TYPICAL REVERSE CHARACTERISTICS



PERCENT OF PEAK REVERSE VOLTAGE,%



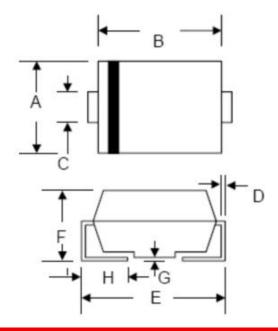
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Mechanical Dimensions SMB



Millimeters		Inches		
SYMBOL	Min.	Max.	Min.	Max.
А	3.30	3.94	0.130	0.155
В	4.06	4.70	0.160	0.185
С	1.80	2.20	0.071	0.087
D	0.152	0.305	0.006	0.012
Е	4.80	5.59	0.189	0.220
F	2.10	2.60	0.083	0.102
G	0.051	0.203	0.002	0.008
Н	0.76	1.52	0.030	0.060

Ordering Information

Device	Package	Shipping	
SD360B	SMB(Pb-Free)	3000pcs / reel	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

 SD360B
 = Part Name

 YY
 = Year

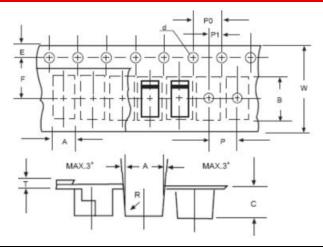
 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Carrier Tape Specification SMB



SYMBOL	Millimeters		
STIVIBUL	Min.	Max.	
Α	3.99	4.19	
В	5.72	5.92	
C	3.23	3.43	
d	1.40	1.60	
E	1.40	1.60	
F	5.60	5.70	
Р	7.90	8.10	
P0	3.90	4.10	
P1	1.90	2.10	
Т	-	0.60	
W	11.80	12.20	

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